Engineering Development Model

RF Transformer TC1-ED5269/5

Impedance Ratio : 1

Important Note

This model has been designed, built and tested in our engineering department. Performance data represents model capability.
At present it is a non-catalog model. On request, we can supply a final specification sheet, part number and price/delivery information.

Please click "Back", and then click "Contact Us" for Applications support.

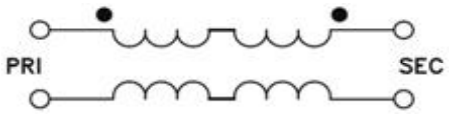
CASE STYLE : AT224-3

ELECTRICAL SPECIFICATIONS 75Ω @ +25°C					
Parameter		**Min.**	**Typ.**	**Max.**	**Units**
Frequency		10		1000	MHz
Insertion Loss *	**3 dB Bandwidth**		10 - 1000		MHz
	2 dB Bandwidth		10 - 1000		MHz
	1 dB Bandwidth		10 - 780		MHz

Note:
* Insertion Loss is referenced to mid-band loss, 0.18dB typ.

MAXIMUM RATINGS	
Operating Temperature	-40°C to 85°C
Storage Temperature	-55°C to 100°C
RF Power	0.25 W
DC Current	30 mA

Configuration : G



PIN CONNECTIONS	
PRIMARY DOT	1
PRIMARY	6
SECONDARY DOT	3
SECONDARY	4